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Editorial

THE JOURNAL OF ELECTRON DEVICES SOCIETY (J-EDS), founded in 2013, has continued along its track of consolidated scientific reputation during 2021.

In 2021, 188 manuscripts were published, more than 400 submitted, three Special Issues were organized and published, while bibliometric indicators kept constant (Journal Impact Factor of 2.484, the year before was 2.555).

The spectrum of topics covered by the published manuscripts shows a healthy diversity, with some areas growing fast, e.g., Solid-State Power and High Voltage Devices and Thin Film Transistors. During 2021 the Editorial board published a detailed Editorial entitled “Quality in Simulation-Only Manuscripts Submitted to J-EDS” which serves as a comprehensive and thoughtful guideline to keep the high-quality standard we expect from papers published on JEDS. This can be found at <https://ieeexplore.ieee.org/document/9410464>.

Such a huge amount of work and quality level could not have been achieved without the dedication, commitment, and professional skill of our Editorial Board, made up by twenty

Editors, and many more high-quality reviewers, to whom I will never be grateful enough.

High-quality and fast review process is the key to success for a scientific publication, but combining at the same time these two, often colliding, figures of merit is not an easy task.

Thanks to the dedication and commitment of the whole Editorial Board, this year the JEDS average time from submission to online post that was set at 10.4 weeks, slightly higher than the year before (9.4) but still a remarkable number.

The following is a list of our reviewers who did a particularly good job as reviewers by virtue of the profoundness, thoroughness, and timeliness of their comments. We hereby greet you and ask our readers to express thanks to all of you.

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ENRICO SANGIORGI received the Laurea degree from the University of Bologna in 1979. He has been a Visiting Scientist with Stanford University and Bell Laboratories. He is Editor-in-Chief of the Journal of the Electron Device Society. He has been Editor of Electron Device Letters for 15 years. From 2015 to 2021 he has been the Vice Rector for Teaching and Education with the University of Bologna. He is a member of the Aeneas Supervisory Board and Chairman of the Aeneas Scientific Council. His research covers the physics, characterization, modeling, and fabrication of solid-state devices and integrated circuits. He has been working on device scaling, its technological, physical, functional limits, and reliability. He is Distinguished Lecturer of the Electron Device Society, Fellow of the IEEE (2005), and he has been member of the following IEEE Committees: Fellow, Cleto Brunetti Award, and Educational Award. He coauthored more than 250 papers that received more than 3,500 citations.